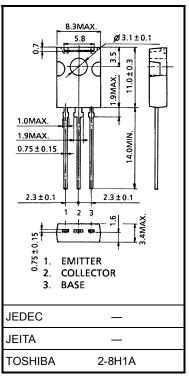
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

2SC3420

Strobe Flash Applications Audio Power Amplifier Applications

- High DC current gain : $h_{FE} = 140 \text{ to } 600 \text{ (VCE} = 2 \text{ V, IC} = 0.5 \text{ A)}$: $h_{FE} = 70 \text{ (min)} \text{ (VCE} = 2 \text{ V, IC} = 4 \text{ A)}$
- Low saturation voltage: V_{CE} (sat) = 1.0 V (max) (IC = 4 A, IB = 0.1 A)
- High collector power dissipation: $P_C = 10 \text{ W} (T_c = 25^{\circ}\text{C}),$ $P_C = 1.5 \text{ W} (T_a = 25^{\circ}\text{C})$

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	50	V	
Collector-emitter voltage		V _{CES}	40	V	
		V _{CEO}	20		
Emitter-base voltage		V _{EBO}	8	V	
Collector current	DC	IC	5		
	Pulse (Note 1)	I _{CP}	8	A	
Base current		Ι _Β	1	А	
Collector power dissipation	Ta = 25°C	Pc	1.5	w	
	Tc = 25°C	ГC	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.82 g (typ.)

Note 1: Pulse test: Pulse width = 10 ms (max) Duty cycle = 30% (max)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

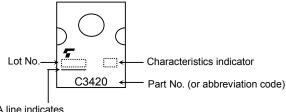
Unit: mm

Electrical Characteristics (Tc = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 40 V, I _E = 0	—	_	100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 8 V, I _C = 0	_	_	100	nA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	20	_	_	V
DC current gain	h _{FE (1)} (Note 3)	V _{CE} = 2 V, I _C = 0.5 A	140	_	600	
	h _{FE (2)}	V _{CE} = 2 V, I _C = 4 A	70	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 4 A, I _B = 0.1 A	_	_	1.0	V
Base-emitter voltage	V _{BE}	V _{CE} = 2 V, I _C = 4 A	_	_	1.5	V
Transition frequency	f _T	V _{CE} = 2 V, I _C = 0.5 A	—	100	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz		40	_	pF

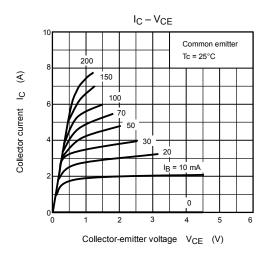
Note 3: h_{FE (1)} classification Y: 140 to 240, GR: 200 to 400, BL: 300 to 600

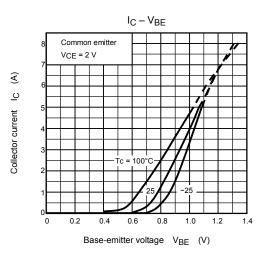
Marking

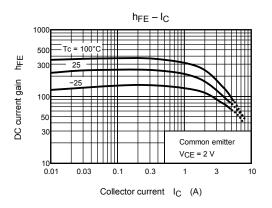


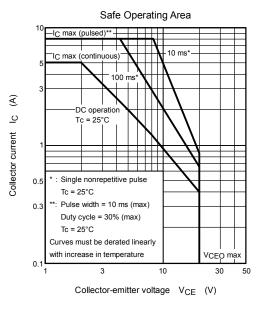
A line indicates lead (Pb)-free package or lead (Pb)-free finish.

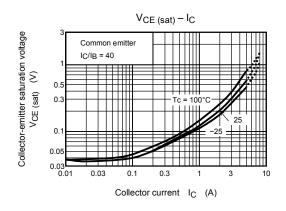
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